



**UTG30N135FQ-S**

Preliminary

*Insulated Gate Bipolar Transistor*

**1350V TRENCH GATE  
FIELD-STOP IGBT**

■ DESCRIPTION

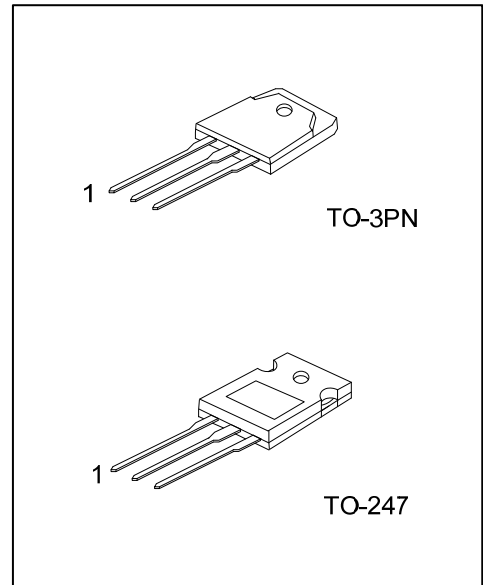
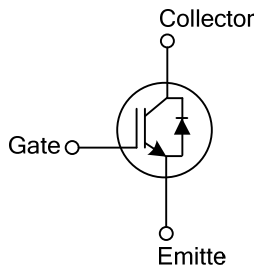
The UTC **UTG30N135FQ-S** is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

The UTC **UTG30N135FQ-S** is suitable for the resonant or soft switching applications.

■ FEATURES

- \* High switching speed
- \* High avalanche ruggedness
- \* Low saturation voltage:  $V_{CE(SAT),Typ.}=1.64V @ I_c=30A, V_{GE}=15V (T_c =25^{\circ}C)$

■ SYMBOL



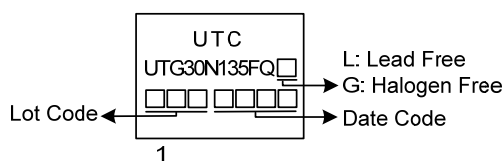
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UTG30N135FQL-T47-R	UTG30N135FQG-T47-R	TO-247	G	C	E	Tape Reel
UTG30N135FQL-T3N-T	UTG30N135FQG-T3N-T	TO-3PN	G	C	E	Tube

Note: Pin Assignment: G: Gate C: Collector E: Emitter

<p>UTG30N135FQG-T47-R</p> <ul style="list-style-type: none"> <li>(1)Packing Type</li> <li>(2)Package Type</li> <li>(3)Green Package</li> </ul>	<ul style="list-style-type: none"> <li>(1) T: Tube</li> <li>(2) T47: TO-247, T3N: TO-3PN</li> <li>(3) G: Halogen Free and Lead Free, L: Lead Free</li> </ul>
--	--

■ MARKING



■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C, unless otherwise noted)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Emitter Voltage	V <sub>CES</sub>	1350	V
Gate-Emitter Voltage	V <sub>GES</sub>	±20	V
Transient Gate-emitter voltage (t <sub>p</sub> < 5 ms)		±25	V
Continuous Collector Current	I <sub>C</sub>	T <sub>C</sub> =25°C	60
		T <sub>C</sub> =100°C	30
Collector Current Pulsed (Note 1)	I <sub>CM</sub>	120	A
Diode Forward Current	I <sub>F</sub>	T <sub>C</sub> =25°C	36
		T <sub>C</sub> =100°C	18
Power Dissipation (T <sub>C</sub> =25°C)	P <sub>D</sub>	TO-247	245
		TO-3P	270
Operating Junction Temperature	T <sub>J</sub>	-40 ~ +175	°C
Storage Temperature Range	T <sub>STG</sub>	-55 ~ +175	°C

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged.  
2. Pulse width limited by maximum junction temperature.

■ THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	θ <sub>JC</sub>	TO-247	0.51
		TO-3P	0.46

■ ELECTRICAL CHARACTERISTICS (T<sub>C</sub>=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>Off Characteristics</b>						
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>		1350			V
Collector Cut-Off Current	I <sub>CES</sub>	V <sub>CE</sub> =1350V, V <sub>GE</sub> =0V			5	μA
G-E Leakage Current	I <sub>GES</sub>	V <sub>CE</sub> =0V, V <sub>GE</sub> =±20V			±400	nA
<b>On Characteristics</b>						
Gate to Emitter Threshold Voltage	V <sub>GE(TH)</sub>	I <sub>C</sub> =250μA, V <sub>CE</sub> =V <sub>GE</sub>	4.5		7.5	V
Collector to Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	I <sub>C</sub> =30A, V <sub>GE</sub> =15V	T <sub>C</sub> =25°C	1.64	2.1	V
			T <sub>C</sub> =125°C	2.0		V
<b>Dynamic Characteristics</b>						
Input Capacitance	C <sub>IES</sub>	V <sub>CE</sub> =25V, V <sub>GE</sub> =0V, f=1MHz		2860		pF
Output Capacitance	C <sub>OES</sub>			96.3		pF
Reverse Transfer Capacitance	C <sub>RES</sub>			30.9		pF
<b>Switching Characteristics</b>						
Total Gate Charge	Q <sub>G</sub>	V <sub>CE</sub> =600V, I <sub>C</sub> =30A, V <sub>GE</sub> =15V		132		nC
Gate-Emitter Charge	Q <sub>GE</sub>			29.5		nC
Gate-Collector Charge	Q <sub>GC</sub>			59.7		nC
Turn-On Delay Time	t <sub>DON)</sub>	V <sub>CC</sub> =600V, I <sub>C</sub> =30A, R <sub>G</sub> =5Ω, V <sub>GE</sub> =0~15V, L=500uH		16.7		ns
Rise Time	t <sub>R</sub>			32.2		ns
Turn-Off Delay Time	t <sub>DOFF)</sub>			120		ns
Fall Time	t <sub>F</sub>			213		ns
Turn-On Switching Loss	E <sub>ON</sub>			2.149		mJ
Turn-Off Switching Loss	E <sub>OFF</sub>			2.207		mJ
<b>SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS</b>						
Forward Voltage Drop	V <sub>F</sub>	I <sub>F</sub> =50A			2.0	V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =30A, dI/dt=100A/μS, V <sub>CC</sub> =400V		54.1		ns
Reverse Recovery Charge	Q <sub>rr</sub>			1.28		μC

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.